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# BLS6G3135-120; BLS6G3135S-120 LDMOS S-Band radar power transistor

**AMPLEON** 

Rev. 3 — 1 September 2015

Product data sheet

#### **Product profile** 1.

### **General description**

120 W LDMOS power transistor intended for radar applications in the 3.1 GHz to 3.5 GHz range.

#### Table 1. **Typical performance**

Typical RF performance at  $T_{case}$  = 25 °C;  $t_D$  = 300  $\mu$ s;  $\delta$  = 10 %;  $I_{Dq}$  = 100 mA; in a class-AB production test circuit.

Mode of operation	f	V <sub>DS</sub>	P <sub>L</sub>	Gp	η <sub>D</sub>	t <sub>r</sub>	t <sub>f</sub>
	(GHz)	(V)	(W)	(dB)	(%)	(ns)	(ns)
pulsed RF	3.1 to 3.5	32	120	11	43	20	6

#### **CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

#### 1.2 Features

- Typical pulsed RF performance at a frequency of 3.1 GHz to 3.5 GHz, a supply voltage of 32 V, an  $I_{Da}$  of 100 mA, a  $t_p$  of up to 300  $\mu s$  with  $\delta$  of 10 %:
  - ◆ Output power = 120 W
  - ◆ Gain = 11 dB
  - ◆ Efficiency = 43 %
- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (3.1 GHz to 3.5 GHz)
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

### 1.3 Applications

■ S-Band power amplifiers for radar applications in the 3.1 GHz to 3.5 GHz frequency range

# 2. Pinning information

Table 2. Pinning

BLS6G3135-120 (SOT502A)  1	
2 gate 3 source [1]	
3 source [1] 3	
2	,∟¹
BLS6G3135S-120 (SOT502B)	2
BLS6G3135S-120 (SOT502B)	3 sym112
1 drain	_
2 gate	ال
3 source [1]	2
	3

<sup>[1]</sup> Connected to flange

# 3. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BLS6G3135-120	-	flanged LDMOST ceramic package; 2 mounting holes; 2 leads	SOT502A			
BLS6G3135S-120	-	earless flanged LDMOST ceramic package; 2 leads	SOT502B			

# 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Min	Max	Unit
$V_{DS}$	drain-source voltage	-	60	V
$V_{GS}$	gate-source voltage	-0.5	+13	V
$I_D$	drain current	-	7.2	Α
$T_{stg}$	storage temperature	-65	+150	°C
T <sub>j</sub>	junction temperature	-	225	°C

# 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Max	Unit
$Z_{\text{th(j-mb)}}$	,	$T_{case}$ = 85 °C; $P_{L}$ = 120 W			
junction to mounting base	$t_p$ = 300 $\mu$ s; $\delta$ = 10 %	0.29	0.40	K/W	
		$t_p = 100 \ \mu s; \ \delta = 20 \ \%$	0.30	0.41	K/W

### 6. Characteristics

Table 6. Characteristics

 $T_i = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.5 \text{ mA}$	60	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS}$ = 10 V; $I_{D}$ = 180 mA	1.4	1.8	2.3	V
I <sub>DSS</sub>	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	5	μΑ
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V$	27	33	-	Α
I <sub>GSS</sub>	gate leakage current	$V_{GS} = 8.3 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	450	nA
9 <sub>fs</sub>	forward transconductance	$V_{DS} = 10 \text{ V}; I_{D} = 9 \text{ A}$	-	13	-	S
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 6.3 \text{ A}$	-	0.085	0.160	Ω

# 7. Application information

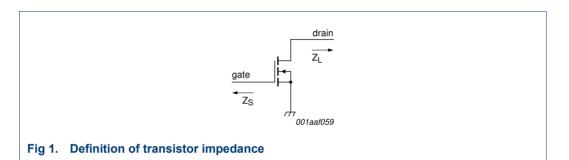
 Table 7.
 Application information

Mode of operation: pulsed RF;  $t_p$  = 300  $\mu$ s;  $\delta$  = 10 %; RF performance at  $V_{DS}$  = 32 V;  $I_{Dq}$  = 100 mA;  $T_{case}$  = 25 °C; unless otherwise specified, in a class-AB production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$P_{L}$	output power		-	120	-	W
$V_{CC}$	supply voltage	P <sub>L</sub> = 120 W	-	-	32	V
Gp	power gain	P <sub>L</sub> = 120 W	9.5	11	-	dB
IRL	input return loss	P <sub>L</sub> = 120 W	6	10	-	dB
P <sub>L(1dB)</sub>	output power at 1 dB gain compression	P <sub>L</sub> = 120 W	-	130	-	W
$\eta_{D}$	drain efficiency	P <sub>L</sub> = 120 W	39	43	-	%
t <sub>r</sub>	rise time	P <sub>L</sub> = 120 W	-	20	50	ns
t <sub>f</sub>	fall time	P <sub>L</sub> = 120 W	-	6	50	ns

Table 8. Typical impedance

f	Z <sub>S</sub>	Z <sub>L</sub>
GHz	Ω	Ω
3.1	2.7 – j5.4	5.9 – j5.9
3.2	3.3 – j4.7	4.5 – j6.2
3.3	4.2 - j4.4	3.5 – j6.0
3.4	5.2 – j4.8	2.7 – j5.6
3.5	5.7 – j6.2	2.0 – j5.2



### 7.1 Ruggedness in class-AB operation

The BLS6G3135-120 and BLS6G3135S-120 are capable of withstanding a load mismatch corresponding to VSWR = 5 : 1 through all phases under the following conditions:  $V_{DS}$  = 32 V;  $I_{Dq}$  = 100 mA;  $P_L$  = 120 W;  $t_p$  = 300  $\mu$ s;  $\delta$  = 10 %.

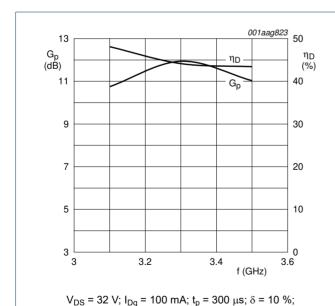
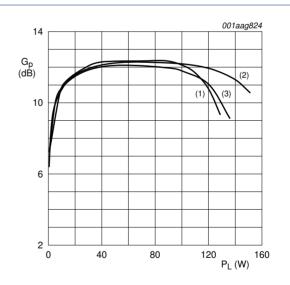


Fig 2. Power gain and drain efficiency as functions of frequency; typical values

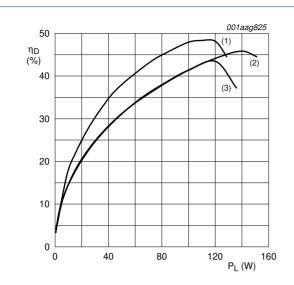


- (1) f = 3.1 GHz
- (2) f = 3.3 GHz
- (3) f = 3.5 GHz

 $V_{DS}$  = 32 V;  $I_{Dq}$  = 100 mA;  $t_p$  = 300  $\mu$ s;  $\delta$  = 10 %.

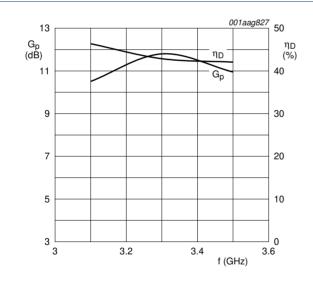
Fig 3. Power gain as a function of load power; typical values

P<sub>L</sub> = 120 W.



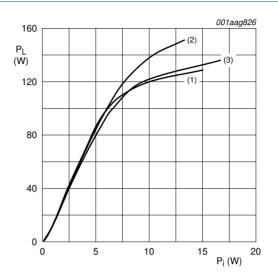
- (1) f = 3.1 GHz
- (2) f = 3.3 GHz
- (3) f = 3.5 GHz  $V_{DS} = 32 \text{ V; } I_{Dq} = 100 \text{ mA; } t_p = 300 \text{ } \mu\text{s; } \delta = 10 \text{ } \%.$

Fig 4. Drain efficiency as a function of load power; typical values



 $V_{DS}$  = 32 V;  $I_{Dq}$  = 100 mA;  $t_p$  = 100  $\mu s;$   $\delta$  = 20 %;  $P_L$  = 120 W.

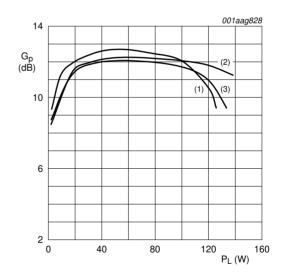
Fig 6. Power gain and drain efficiency as functions of frequency; typical values



- (1) f = 3.1 GHz
- (2) f = 3.3 GHz
- (3) f = 3.5 GHz

 $V_{DS}$  = 32 V;  $I_{Dq}$  = 100 mA;  $t_p$  = 300  $\mu$ s;  $\delta$  = 10 %.

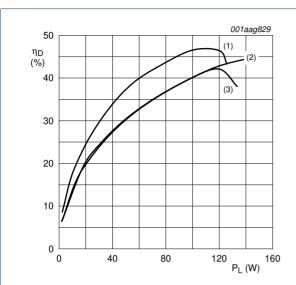
Fig 5. Load power as a function of input power; typical values



- (1) f = 3.1 GHz
- (2) f = 3.3 GHz
- (3) f = 3.5 GHz

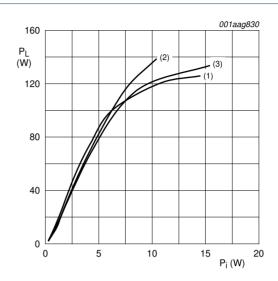
 $V_{DS}$  = 32 V;  $I_{Dq}$  = 100 mA;  $t_p$  = 100  $\mu s; \, \delta$  = 20 %.

Fig 7. Power gain as a function of load power; typical values



- (1) f = 3.1 GHz
- (2) f = 3.3 GHz
- (3) f = 3.5 GHz  $V_{DS} = 32 \text{ V}; \ I_{Dq} = 100 \text{ mA}; \ t_p = 100 \ \mu\text{s}; \ \delta = 20 \ \%.$

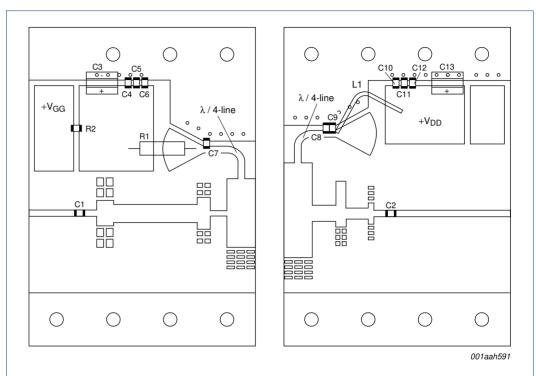
Fig 8. Drain efficiency as a function of load power; typical values



- (1) f = 3.1 GHz
- (2) f = 3.3 GHz
- (3) f = 3.5 GHz  $V_{DS} = 32 \text{ V; } I_{Dq} = 100 \text{ mA; } t_p = 100 \text{ } \mu\text{s; } \delta = 20 \text{ } \%.$

Fig 9. Load power as a function of input power; typical values

### 8. Test information



Striplines are on a double copper-clad Rogers Duroid 6006 Printed-Circuit Board (PCB) with  $\epsilon_r$  = 6.2 and thickness = 0.64 mm.

See Table 9 for list of components.

Fig 10. Component layout for 3.1 GHz to 3.5 GHz MHz test circuit

#### Table 9. List of components (see Figure 10)

To ensure good power supply of the device, adding an electrolytical capacitor close to the supply connection of the circuit may be required. The actual capacitor value may differ depending on the pulse format, the quality of the power supply and the length of the connecting wires to the power supply. In general a value of  $470 \, \mu F$  will be sufficient.

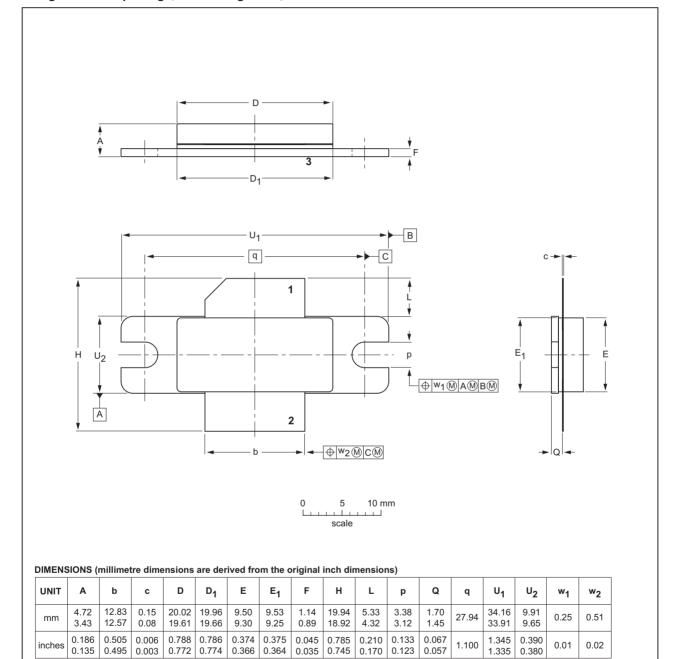
Component	Description	Value	Remarks
C1, C2, C4, C5, C6, C7, C8, C9, C11	multilayer ceramic chip capacitor	24 pF	<u>[1]</u>
C3	electrolytic capacitor	20 μF; 20 V	
C10	multilayer ceramic chip capacitor	33 pF	[1]
C12	multilayer ceramic chip capacitor	1 nF	[2]
C13	electrolytic capacitor	100 μF; 63 V	
L1	copper wire	-	
R1	resistor	49.9 Ω	
R2	SMD resistor	49.9 Ω	

- [1] American Technical Ceramics type 100A or capacitor of same quality.
- [2] American Technical Ceramics type 700A or capacitor of same quality.

#### Package outline 9.

Flanged ceramic package; 2 mounting holes; 2 leads

SOT502A

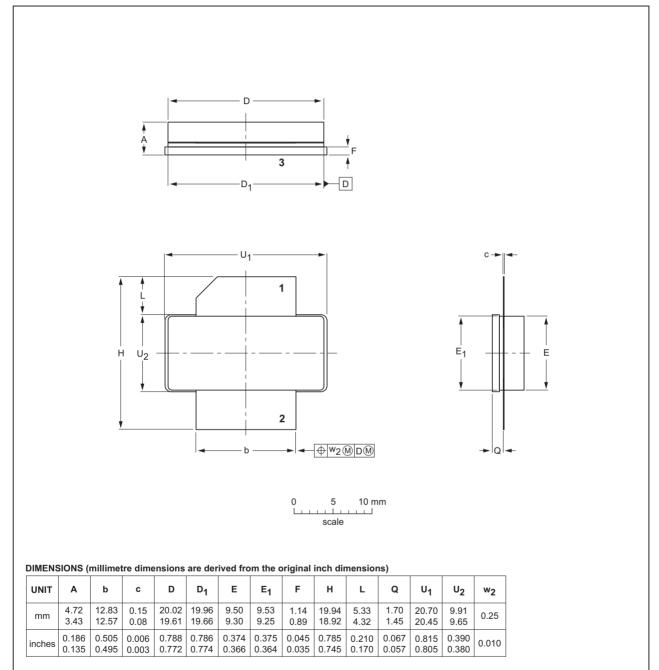


OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT502A					<del>-03-01-10</del> 12-05-02

Fig 11. Package outline SOT502A

### Earless flanged ceramic package; 2 leads

SOT502B



OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT502B						<del>-07-05-09-</del> 12-05-02

Fig 12. Package outline SOT502B

# 10. Abbreviations

Table 10. Abbreviations

Acronym	Description
LDMOS	Laterally Diffused Metal Oxide Semiconductor
LDMOST	Lateral Diffused Metal-Oxide Semiconductor Transistor
RF	Radio Frequency
S-Band	Short wave Band
VSWR	Voltage Standing-Wave Ratio

# 11. Revision history

### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLS6G3135-120_6G3135S-120#3	20150901	Product data sheet		BLS6G3135-120_6G3135S -120#2
Modifications:	<ul> <li>The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>			
BLS6G3135-120_6G3135S-120#2	20080529	Product data sheet	-	BLS6G3135-120_6G3135S -120#1
BLS6G3135-120_6G3135S-120#1	20070814	Preliminary data sheet	-	-

# 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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# BLS6G3135-120; BLS6G3135S-120

**LDMOS S-Band radar power transistor** 

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# BLS6G3135-120; BLS6G3135S-120

# **AMPLEON**

**LDMOS S-Band radar power transistor** 

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